Amplifier Transistors

Voltage and Current are Negative for PNP Transistors

Features

Pb–Free Packages are Available*

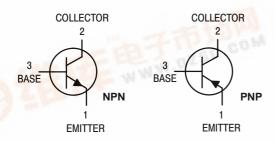


Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V_{CEO}	20	Vdc
Collector – Emitter Voltage	V _{CES}	25	Vdc
Emitter – Base Voltage	V _{EBO}	5.0	Vdc
Collector Current – Continuous	I _C	1.0	Adc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction_to_Ambient	R _θ JA	200	°C/W
Thermal Resistance, Junction-to-Case	R _θ JC	83.3	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

pdf.dzsc.com



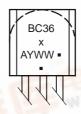
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TO-92 CASE 29 STYLE 14

MARKING DIAGRAMS





BC36x = Device Code

x = 8 or 9

A = Assembly Location

Y = Year
WW = Work Week
Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

CITE ENTITE IN CITED IN				
Device	Package	Shipping		
BC368	TO-92	5000 Units/Box		
BC368G	TO-92 (Pb-Free)	5000 Units/Box		
BC368ZL1	TO-92	2000/Ammo Box		
BC368ZL1G	TO-92 (Pb-Free)	2000/Ammo Box		
BC369	TO-92	5000 Units/Box		
BC369G	TO-92 (Pb-Free)	5000 Units/Box		
BC369ZL1	TO-92	2000/Ammo Box		
BC369ZL1G	TO-92 (Pb-Free)	2000/Ammo Box		

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (I _C = 10 mA, I _B = 0)	V _{(BR)CEO}	20	_	-	Vdc
Collector – Base Breakdown Voltage (I _C = 100 μA, I _E = 0)	V _{(BR)CBO}	25	_	-	Vdc
Emitter – Base Breakdown Voltage $(I_E = 100 \mu A, I_C = 0)$	V _{(BR)EBO}	5.0	_	-	Vdc
Collector Cutoff Current $(V_{CB} = 25 \text{ V}, I_E = 0)$ $(V_{CB} = 25 \text{ V}, I_E = 0, T_J = 150^{\circ}\text{C})$	I _{CBO}	- -	_ _	10 1.0	μAdc mAdc
Emitter Cutoff Current $(V_{EB} = 5.0 \text{ V}, I_{C} = 0)$	I _{EBO}	-	_	10	μAdc
ON CHARACTERISTICS					
DC Current Gain $ (V_{CE} = 10 \text{ V}, I_{C} = 5.0 \text{ mA}) $ $ (V_{CE} = 1.0 \text{ V}, I_{C} = 0.5 \text{ A}) $ BC368, 369 $ (V_{CE} = 1.0 \text{ V}, I_{C} = 1.0 \text{ A}) $		50 85 170 60	- - - -	- 375 375 -	-
Bandwidth Product ($I_C = 10 \text{ mA}$, $V_{CE} = 5.0 \text{ V}$, $f = 20 \text{ MHz}$)	f _T	65	_	-	MHz
Collector–Emitter Saturation Voltage (I _C = 1.0 A, I _B = 100 mA)	V _{CE(sat)}	-	_	0.5	V
Base–Emitter On Voltage (I _C = 1.0 A, V _{CE} = 1.0 V)	V _{BE(on)}	-	_	1.0	V

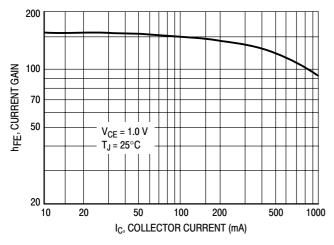


Figure 1. DC Current Gain

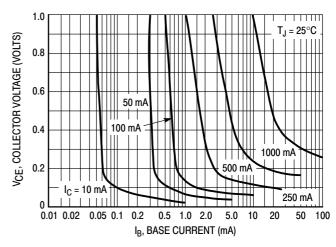


Figure 2. Collector Saturation Region

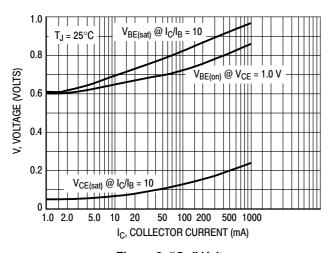


Figure 3. "On" Voltages

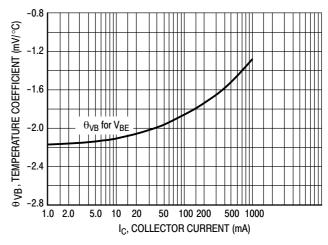


Figure 4. Temperature Coefficient

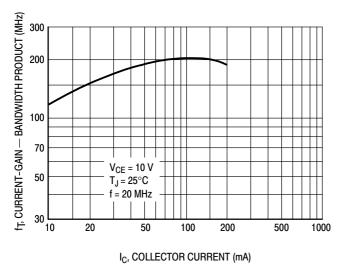


Figure 5. Current-Gain — Bandwidth Product

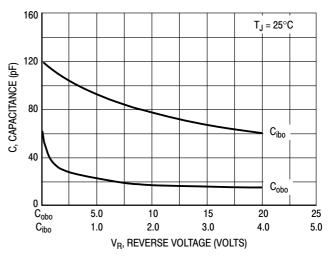
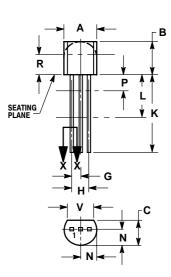


Figure 6. Capacitance

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AL





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
- 3. CONTOUR OF PACKAGE BEYOND DIMENSION R
 IS UNCONTROLLED.
- 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

STYLE 14:
PIN 1. EMITTER
2. COLLECTOR
3. BASE

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